This application note provides an overview of Nexperia's discrete IGBT products. It contains a brief technology overview, and discusses the static and dynamic performances of the NGW30T60M3DF compared to competitor products. Finally, a selection guide is included.
1. Introduction

Since their introduction, Insulated Gate Bipolar Transistors (IGBT) have become one of the most commonly used electronic components. They are central to the inverters found in drivers, battery chargers, as well as solar and wind plants. With the increasing global focus on renewable energy and demand for efficiency, having a reliable and robust package is critical for industries to stay competitive. Nexperia’s line of IGBT products are optimized for fast switching and low power losses in a small footprint. This application note is an introduction to Nexperia’s current IGBT product line, providing a brief technology overview, and a selection guide.

2. Technology overview

Nexperia’s proprietary IGBT products feature a robust and cost-effective Carrier-Stored, Trench Gate advanced Field Stop (FS) construction (see Fig. 1). Nexperia’s IGBTs utilize either a punch-through or a shorted-anode structure to maximize power density in a small package. Package types currently available include the TO247-3L and the TO247-3L-PLUS, with additional packages in development.

Functionally, IGBTs are essentially almost-ideal switches. A positive voltage across the gate-emitter allows current to flow through the collector; a negative voltage disrupts this flow. Because of the capacitive nature of the gate-emitter junction, only a very tiny gate current is required to charge the gate. The presence of a gate charge, however small, must be considered when incorporating IGBTs into product designs.

The gate charge also translates into energy loss. There is always a trade-off between switching losses, conduction losses, and the ability to withstand a short circuit. For example, a reduced switching loss means a higher conduction loss and reduced short circuit capacity.

While some modern power electronic devices have efficiency levels exceeding 99%, the heat generated by the energy loss can be tremendous. A throughput of over 10 MW is not unusual for commercial applications; even at an efficiency level of 99%, that means 100 kW is lost, mostly as heat. Currently heat dissipation represents one of the key limiting factors for IGBT use.

Nevertheless, IGBTs have numerous applications that require a broad range of currents and voltages. They are often used in home appliances, but also have industrial applications, such as for welding, solar inverters, uninterruptible power supplies, and chargers for electric vehicles. Nexperia’s IGBT line have been developed with industrial applications such as motor control, photo-voltaic, UPS and EV chargers in mind, and have been optimized to provide a highly competitive option.

![Fig. 1. Structure of Nexperia’s IGBT](image-url)
3. Description or product family

Nexperia's IGBT line offers a broad range of current and voltage ratings. Designers can choose between IGBTs with medium speed (M3) and high speed (H3) switching capabilities. Products in the M3 line are characterized by low conduction losses and switching losses. These are intended for applications which require a switching frequency of less than 20 kHz, such as motor drivers. Products in the H3 line are characterized by low switching losses and conduction losses, and are intended for applications which require switching frequency of up to 50 kHz, such as solar inverters, and welding. In both categories, the IGBT and integrated emitter-collector diode are optimized for peak performance.

To make selection simpler Nexperia’s IGBT nomenclature follows the fairly standard convention where the first number represents the current rating and the second number represents 1/10 of the voltage rating. See Fig. 2 for additional information.

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![Fig. 2. Nomenclature of Nexperia’s IGBT product line](image)

Nexperia's IGBT family is divided according to Fig. 3

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![Fig. 3. Nexperia's IGBT product line taxonomy](image)
4. IGBT static performance

Nexperia's M3 IGBT have a very low collector-emitter saturation voltage over a wide range of collector currents and junction temperatures (see Fig. 4). This results in the following benefits at a systems level:

- Improving conduction losses in the system
- Higher system efficiency
- Small heatsink size

Compared to the competitor's product, Nexperia's NGW30T60M3DF have a reduced $V_{CE(sat)}$ across a wide range of collector currents. At the rated current (30A), this reduction is by 100 mV at 25 °C and 150 mV at 175 °C.

Where $V_{CE} = 15$ V
(1) NGW30T60M3DF at 25 °C
(2) Competitor IGBT at 25 °C
(3) NGW30T60M3DF at 175 °C
(4) Competitor IGBT at 175 °C

Fig. 4. Collector current as a function of collector-emitter voltage; Nexperia NGW30T60M3DF vs. competitor
5. IGBT dynamic performance

Nexperia’s M3 IGBTs perform very well under switching conditions. This results in low switching losses at a systems level. Fig. 5 and Fig. 6 show the relationship between $E_{\text{off}}$ losses and $I_C$ and $r_G$, respectively. In both cases the $E_{\text{off}}$ losses are significantly less than that of the competitor product.

Nexperia’s M3 IGBT reduced $E_{\text{off}}$ as a function of the switching current (rated for 30A in this example) was approximately 200 $\mu$J at 25 °C and 352 $\mu$J at 175 °C. As the typical operating current range is between half and full nominal current, Nexperia’s M3 IGBT maintains the lower $E_{\text{off}}$ losses over a wide range of $r_G$ and emitter current.

Fig. 5. $E_{\text{off}}$ losses as a function of switching current

Where $V_{CE} = 400$ V; $r_G = 10$ Ω
(1) NGW30T60M3DF at 25 °C
(2) NGW30T60M3DF at 175 °C
(3) Competitor IGBT at 25°C
(4) Competitor IGBT at 175 °C

Fig. 6. $E_{\text{off}}$ losses as a function of $r_G$

Where $V_{CE} = 400$ V, $I_C = 30$ A
(1) NGW30T60M3DF at 25 °C
(2) NGW30T60M3DF at 175 °C
(3) Competitor IGBT at 25 °C
(4) Competitor IGBT at 175 °C
6. Power loss simulation in motor drive applications

Modern motor drives must control motor speed, position, and torque with high precision. Nexperia has optimized the trade-off between switching losses and conduction losses to make the M3 IGBT suitable for motor drive applications. See Fig. 7. Simulations were done to assess the switching loss and conduction loss in the NGW30T60M3DF under loaded conditions, and to compare the performance with competitor products.

Fig. 7. Motor drive application diagram

The simulation conditions are shown in Table 1. The NGW30T60M3DF was compared to the competitor IGBT and the top-of-the-line IGBT currently available in the market (premium).

Table 1. Simulation details

<table>
<thead>
<tr>
<th>Test conditions</th>
<th></th>
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<tbody>
<tr>
<td>( V_{DC} )</td>
<td>400 V</td>
</tr>
<tr>
<td>( I_{rm} )</td>
<td>30 A</td>
</tr>
<tr>
<td>( f_{sw} ) (switching frequency)</td>
<td>10 kHz</td>
</tr>
<tr>
<td>modulation index</td>
<td>0.8</td>
</tr>
<tr>
<td>( \cos ) (power factor)</td>
<td>0.8</td>
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</tbody>
</table>

The results are summarized in Fig. 8.

Fig. 8. Switching and conduction losses; Nexperia's IGBT vs. competitor IGBT
In conclusion:

- Nexperia’s M3 IGBT are optimized for good trade-off according to target switching frequencies.
- Nexperia’s M3 IGBT have an approximately 15% improvement in energy loss over the direct competitor and a slight improvement against the premium competitor.
- Compared with the competitor products, Nexperia’s M3 IGBT shows lowest switching losses.
- Nexperia’s IGBT low power losses meet energy efficiency requirements and increase design margin and reliability.

7. Selection guide

**Table 2** contains the main characteristics of M3 and H3 IGBT products and general application fields.

<table>
<thead>
<tr>
<th>Product family</th>
<th>Feature</th>
<th>Applications</th>
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</thead>
<tbody>
<tr>
<td></td>
<td>Low conduction losses and minimized switching losses</td>
<td>Industrial and home appliance motor driver</td>
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<td></td>
<td>Stable and tight parameter for easy parallel operation</td>
<td>Solar string inverters</td>
</tr>
<tr>
<td></td>
<td>Maximum junction temperature 175 °C</td>
<td>Uninterruptible power Inverter Suppliers</td>
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<tr>
<td></td>
<td>Soft fast reverse recovery diode</td>
<td></td>
</tr>
<tr>
<td></td>
<td>5-8 μs short-circuit capability at high temperature</td>
<td></td>
</tr>
<tr>
<td></td>
<td>RoHS compliant and Pb-free lead plating</td>
<td></td>
</tr>
<tr>
<td></td>
<td>Enabling outstanding system efficiency and reliability</td>
<td></td>
</tr>
<tr>
<td></td>
<td>Low conduction losses and minimized saturation voltage $V_{CE(sat)}$</td>
<td>Home appliance PFC</td>
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<tr>
<td></td>
<td>Stable and tight parameters for easy parallel operation</td>
<td>Solar string inverters</td>
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<tr>
<td></td>
<td>Maximum junction temperature 175 °C</td>
<td>Uninterruptible power Inverter Suppliers</td>
</tr>
<tr>
<td></td>
<td>Soft fast reverse recovery diode</td>
<td>Induction Heating</td>
</tr>
<tr>
<td></td>
<td>Optimized for high speed hard and soft switching</td>
<td>Welding</td>
</tr>
<tr>
<td></td>
<td>RoHS compliant and Pb-free lead plating</td>
<td></td>
</tr>
<tr>
<td></td>
<td>Enabling outstanding system efficiency and reliability</td>
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</table>

Applications

- Industrial and home appliance motor driver
- Solar string inverters
- Uninterruptible power Inverter Suppliers
- Induction Heating
- Welding

Typical switching frequency ranges of different IGBT products are shown in **Fig. 9**.

![Fig. 9. Recommended switching frequency of MS and HS IGBT](image-url)
8. Abbreviations

<table>
<thead>
<tr>
<th>Acronym</th>
<th>Description</th>
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<tr>
<td>H3</td>
<td>High Speed 3</td>
</tr>
<tr>
<td>IGBT</td>
<td>Insulated Gate Bipolar Transistor</td>
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<tr>
<td>M3</td>
<td>Medium Speed 3</td>
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<tr>
<td>RoHS</td>
<td>Restriction of Hazardous Substances</td>
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<tr>
<td>UPS</td>
<td>Uninterruptible Power Supply</td>
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9. Revision history

<table>
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<th>Revision number</th>
<th>Date</th>
<th>Description</th>
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